

## MPSH34

# **NPN General Purpose Amplifier**

- This device is designed for common-emitter low noise amplifier and mixer applications with collector currents in the 100mA to 20mA range to 300MHz, and low frequency drift common-base VHF oscillator applications with high output levels for driving FET mixers.
- Sourced from process 47.
- See MPSH11 for characteristics.



1. Base 2. Emitter 3. Collector

## **Absolute Maximum Ratings** T<sub>a</sub>=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CEO</sub>	Collector-Emitter Voltage	40	V
$V_{CBO}$	Collector-Base Voltage	40	V
V <sub>EBO</sub>	Emitter-Base Voltage	4.0	V
I <sub>C</sub>	Collector current - Continuous	50	mA
T <sub>J</sub> , T <sub>stg</sub>	Junction and Storage Temperature	-55 ~ +150	°C

## **Electrical Characteristics** T<sub>a</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
Off Charact	eristics			•	
V <sub>(BR)CEO</sub>	Collector-Emitter Sustaining Voltage *	$I_C = 1.0 \text{mA}, I_B = 0$	40		V
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	$I_C = 100 \mu A, I_E = 0$	40		
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	$I_E = 10\mu A, I_C = 0$	4.0		VV
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = 30V, I <sub>E</sub> = 0		50	nA
On Charact	eristics				
h <sub>FE</sub>	DC Current Gain	$V_{CE} = 2.0V, I_{C} = 20mA$ $V_{CE} = 15V, I_{C} = 7.0mA$	15 40		
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 7.0mA, I <sub>B</sub> = 2.0mA		0.5	V
V <sub>BE(on)</sub>	Base-Emitter On Voltage	$V_{CE} = 15V, I_{C} = 7.0 \text{mA}$		0.95	V
	I Characteristics				
f <sub>T</sub>	Current Gain Bandwidth Product	$I_C = 15mA, V_{CE} = 15V,$ f = 100MHz	500		MHz
C <sub>cb</sub>	Collector-Base Capacitance	$V_{CB} = 10V, I_E = 0, f = 1.0MHz$		0.32	pF

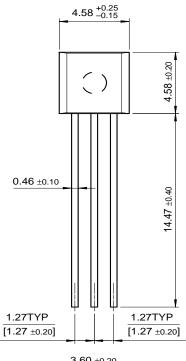
<sup>\*</sup> Pulse Test: Pulse Width ≤ 300μs, Duty Cycle ≤ 2.0%

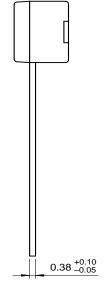
## Thermal Characteristics T<sub>A</sub>=25°C unless otherwise noted

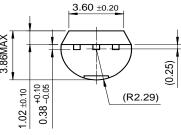
Symbol	Parameter	Max.	Units	
P <sub>D</sub>	Total Device Dissipation	625	mW	
	Derate above 25°C	5.0	mW/°C	
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3	°C/W	
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	°C/W	

# **Package Dimensions**

TO-92







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The Power Franch Programmable Ac	nise™		<b>.</b>	
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